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NTE74HC574
Integrated Circuit
TTL – High Speed CMOS,
Octal D–Type Flip–Flop with 3–State Outputs
Common Output Control and Common Clock

Description:

The NTE74HC574 is a high speed octal D–type flip–flop with 3–state outputs in a 20–Lead DIP type package with the capability to drive 15 LS–TTL loads. The eight edge–triggered flip–flops enter data into their registers on the LOW to HIGH transition of clock (CP). The output enable ($\overline{OE}$) controls the 3–state outputs and is independent of the register operation. When $\overline{OE}$ is HIGH, the outputs are in the high–impedance state.

Features:

- Wide Power Supply Range: 2V to 6V
- High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- Buffered Inputs
- Common Three–State Output Enable Control
- Three–State Outputs
- Bus Line Driving Capability
- Typical Propagation Delay (Clock to Q): 15ns at V_{CC} = 5V, C_L = 15pF, T_A = +25°C
- Fanout (Over Temperature Range):
  - Standard Outputs . . . 10 LS–TTL Loads
  - Bus Driver Outputs . . 15 LS–TTL Loads

Absolute Maximum Ratings: (Note 1, Note 2)

Supply Voltage, V_{CC} . . . . . –0.5 to +7.0V
Clamp Diode Current, I_{IK}, I_{OK} . . . . . ±20mA
DC Drain Current (Per Output), I_{OUT} . . . . . ±35mA
DC Output Source or Sink Current (Per Output), I_{OUT} . . . . . ±25mA
DC V_{CC} or GND Current (Per Pin), I_{CC} . . . . . ±50mA
Maximum Junction, T_J . . . . . +150°C
Storage Temperature Range, T_{stg} . . . . . –65°C to +150°C
Typical Thermal Resistance, Junction–to–Ambient, R_{thJA} . . . . . 69°C/W
Lead Temperature (During Soldering, 10sec), T_L . . . . . +300°C

Note 1. Absolute Maximum Ratings are those values beyond which damage to the device may occur.
Note 2. Unless otherwise specified, all voltages are referenced to GND.

Recommended Operating Conditions:

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	2.0	–	6.0	V
DC Input or Output Voltage	V_{IN}, V_{OUT}	0	–	V_{CC}	V
Operating Temperature Range	T_A	–40	–	+85	°C
Input Rise or Fall Times	t_r, t_f				
V_{CC} = 2.0V		–	–	1000	ns
V_{CC} = 4.5V		–	–	500	ns
V_{CC} = 6.0V		–	–	400	ns

DC Electrical Characteristics:

Parameter	Symbol	Test Conditions		V_{CC}	T_A = +25°C	T_A = –40° to +85°C		Unit
					Typ	Guaranteed Limits		
Minimum HIGH Level Input Voltage	V_{IH}			2.0	–	1.5	1.5	V
				4.5	–	3.15	3.15	V
				6.0	–	4.2	4.2	V
Maximum LOW Level Input Voltage	V_{IL}			2.0	–	0.5	0.5	V
				4.5	–	1.35	1.35	V
				6.0	–	1.8	1.8	V
Minimum HIGH Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OUT} = –20μA	–	V_{CC}	V_{CC} –0.1	V_{CC} –0.1	V
			I_{OUT} = –6mA	4.5	–	3.98	3.84	V
			I_{OUT} = –7.8mA	6.0	–	5.48	5.34	V
Minimum LOW Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OUT} = 20μA	–	–	0.1	0.1	V
			I_{OUT} = 6mA	4.5	0.2	0.26	0.33	V
			I_{OUT} = 7.8mA	6.0	0.2	0.26	0.33	V
Maximum Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	–	±0.1	±1.0	μA
Maximum Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND, I_{OUT} = 0μA		6.0	–	8.0	80	μA
Three–State Leakage Current	I_{OZ}	V_{IN} = V_{IH} or V_{IL}		6.0	–	±0.5	±5.0	μA

Prerequisite for Switching Specifications:

Parameter	Symbol	Test Conditions	V_{CC}	T_A = +25°C	T_A = –40° to +85°C		Unit
				Typ	Guaranteed Limits		
Maximum Clock Frequency	f_{MAX}		2.0	–	6	5	MHz
			4.5	–	30	25	MHz
			6.0	–	35	29	MHz
Clock Pulse Width	t_W		2.0	–	80	100	ns
			4.5	–	16	20	ns
			6.0	–	14	17	ns
Setup Time (Date to Clock)	t_{SU}		2.0	–	60	75	ns
			4.5	–	12	15	ns
			6.0	–	10	13	ns
Hold Time (Date to Clock)	t_H		2.0	–	5	5	ns
			4.5	–	5	5	ns
			6.0	–	5	5	ns

Switching Specifications: ($t_r = t_f$ = 6ns unless otherwise specified)

Parameter	Symbol	Test Conditions	V_{CC}	T_A = +25°C	T_A = −40° to +85°C		Unit
				Typ	Guaranteed Limits		
Propagation Delay Time (Clock to Output)	t_{PLH}, t_{PHL}	C_L = 50pF	2.0	–	165	205	ns
			4.5	–	33	41	ns
		C_L = 15pF	5.0	15	–	–	ns
		C_L = 50pF	6.0	–	28	35	ns
Propagation Delay Time (Disable to Q)	t_{PLZ}, t_{PHZ}	C_L = 50pF	2.0	–	135	170	ns
			4.5	–	27	34	ns
		C_L = 15pF	5.0	11	–	–	ns
		C_L = 50pF	6.0	–	23	29	ns
Propagation Delay Time (Output Enable to Q)	t_{PZL}, t_{PZH}	C_L = 50pF	2.0	–	150	190	ns
			4.5	–	30	38	ns
		C_L = 15pF	5.0	12	–	–	ns
		C_L = 50pF	6.0	–	26	33	ns
Maximum Clock Frequency	f_{MAX}	C_L = 15pF	5.0	60	–	–	MHz
Output Transition Time	t_{TLH}, t_{THL}	C_L = 50pF	2.0	–	60	75	ns
			4.5	–	12	15	ns
			6.0	–	10	13	ns
Maximum Input Capacitance	C_{IN}		–	–	10	10	pF
Minimum Three−State Output Capacitance	C_O		–	–	20	20	pF
Power Dissipation Capacitance	C_{PD}	C_L = 15pF, Note 3	5.0	39	–	–	pF

Note 3. C_{PD} is used to determine the dynamic power consumption, per channel.
$P_D = C_{PD} V_{CC}^2 fi + \Sigma V_{CC}^2 f_O C_L$ where f_i = Input Frequency, f_O = Output Frequency,
C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Truth Table:

Inputs			Output
$\overline{OE}$	CP	Data D_n	Q_n
L	↑	H	H
L	↑	L	L
L	L	X	Q0
H	X	X	Z

H = HIGH Level (Steady State)
L = LOW Level (Steady State)
X = Don't Care
↑ = Transition from LOW to HIGH Level
Q0 = The level of Q before the indicated steady state input conditions were established.
Z = High Impedance State

Pin Connection Diagram